Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.025 inches

Mounting Facility Quantity:

- 1
- Mounting Method:

Threaded stud

Overall Width Across Flats:

0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

400.0 reverse voltage, instantaneous and 10.0 gate voltage, dc

Current Rating Per Characteristic:

8.00 amperes source cutoff current preset and 6.00 amperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Case may contain beryllium oxide - handle and dispose iaw hazmat procedures

Test Data Document:

06481-932047 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0